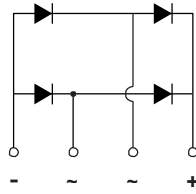
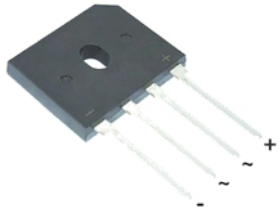


**GBU**



**Features**

- ROHS compliant
- Glass passivated chip
- High forward surge capability
- Meet MSL level 1, per J-STD-020  
LF maximum peak of 250 °C
- Solder dip 260 °C / 40S
- Component in accordance to ROHS 2002/95/EC and WEEE 2002/96/WC
- UL recognition, file number E342874



**Primary characteristics**

$I_{F(AV)}$	4.0A
$V_{RRM}$	200V to 800V
$I_{FSM}$	80A
$I_{RM}$	5uA
$V_{FM}$ at $I_F=2A$	1.0V
$T_J$ max.	150 °C

**Applications**

Ideal for ac-to-dc bridge full wave rectification such as SMPS, home appliances, office equipment, industrial automation applications

**Mechanical data**

- Case: GBU
- Epoxy meets UL 94 V-0 flammability rating
- Terminals: Tin plated leads.
- Polarity: As marked.
- Mounting Torque: 10cm·kg (8.8 inches·lbs) max.
- Recommended Torque: 5.7 cm·kg (5 inches·lbs)

**Maximum rating (Ta=25°C unless otherwise noted)**

Parameter	Sym	GBU			Unit
		4A02	4A06	4A08	
Max. repetitive peak reverse voltage	$V_{RRM}$	200	600	800	V
Max. RMS reverse voltage	$V_{RMS}$	140	420	560	V
Max. DC blocking voltage	$V_{DC}$	200	600	800	V
Max. average forward current	$I_{F(AV)}$	4A			A
Non-repetitive peak forward surge current 8.3ms single half-sine-wave	$I_{FSM}$	80			A
Rating for fusing, $1ms \leq t \leq 8.3ms$	$I^2t$	27			A <sup>2</sup> S
Max. instantaneous forward voltage drop per diode	$V_{FM}$	1.0(2A)			V
Max. instantaneous reverse current at rated DC blocking voltage	$I_{RM}$	Ta=25 °C	5		μA
		Ta=125 °C	400		μA
Operating junction temperature	$T_J$	-55 ~ +150			°C
Storage temperature	$T_{STG}$	-55 ~ +150			°C
Thermal resistance junction to ambient (Note2)	$R_{J-A}$	27			°C/W
Thermal resistance junction to cover (Note1)	$R_{J-C}$	5			°C/W

**Notes**

- (1) Unit case mounted on aluminum plate heatsink
- (2) Units mounted on PCB with 0.5" x 0.5" (12 mm x 12 mm) copper pads and 0.375" (9.5 mm) lead length



Ordering information (Example)

PREFERRED	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
GBU4A06	3.404	45	20	Tube
GBU4A06	3.404	51	250	Paper tray

Typical characteristics

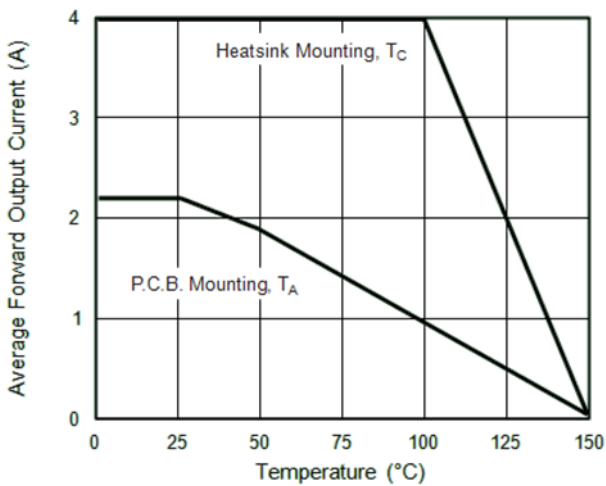
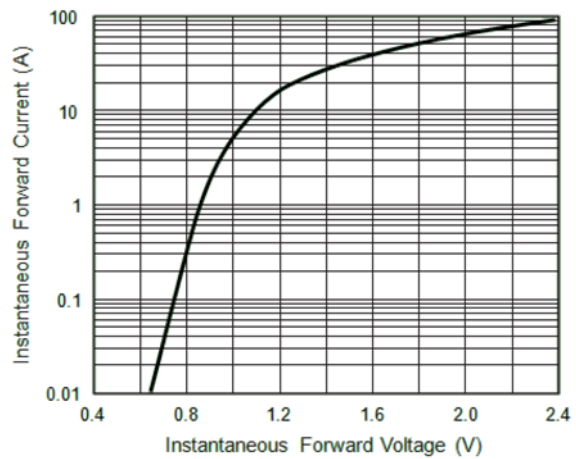
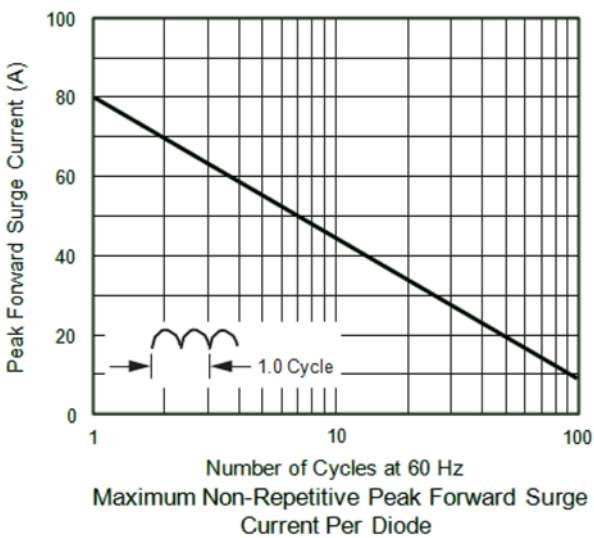


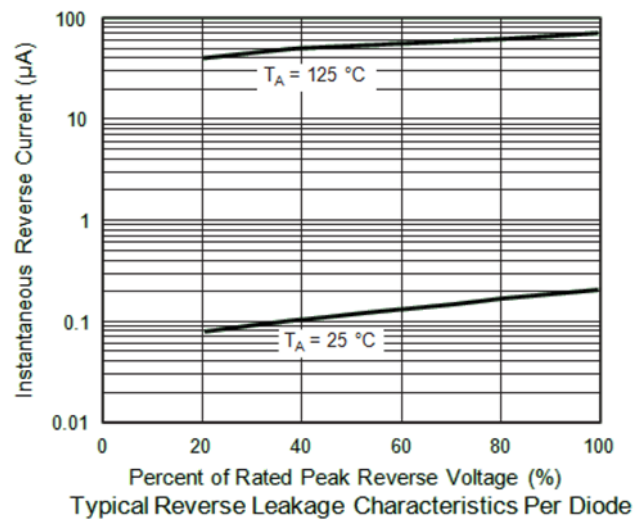
Fig. 1 - Derating Curve Output Rectified Current



Typical Instantaneous Forward Characteristics Per Diode

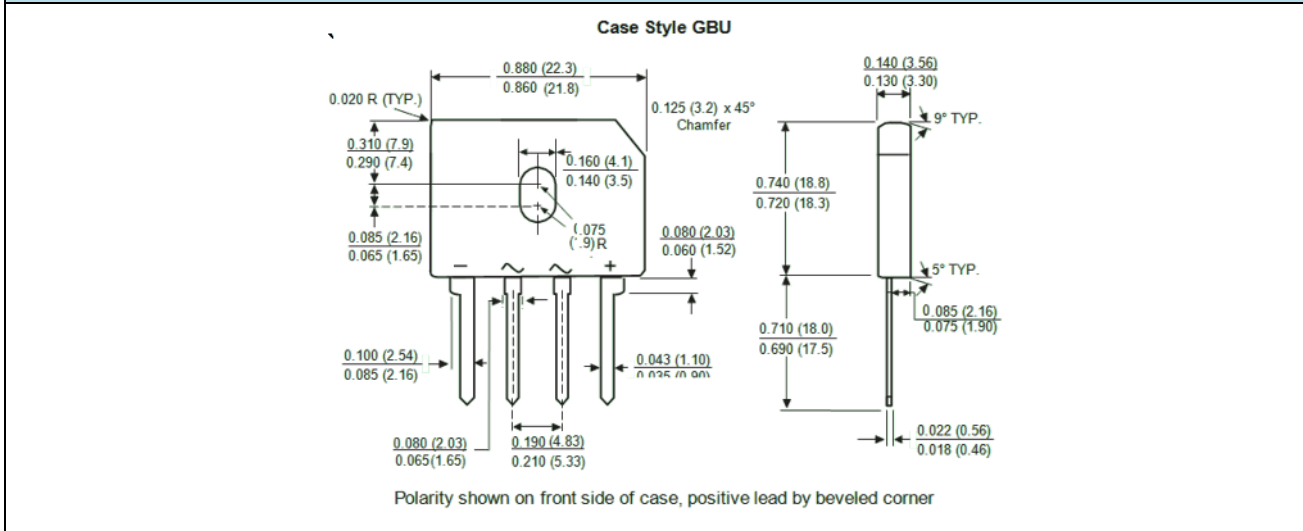


Maximum Non-Repetitive Peak Forward Surge Current Per Diode



Typical Reverse Leakage Characteristics Per Diode

**Package outline dimensions**



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